

compound transistor μ PA102

HIGH FREQUENCY NPN TRANSISTOR ARRAY

FEATURES

- TWO BUILT-IN DIFFERENTIAL AMPLIFIER CIRCUITS: (Each Transistor has fτ 9 GHz)
- OUTSTANDING her LINEARITY
- TWO PACKAGE OPTIONS:

μPA102B: Superior thermal dissipation due to studded 14-pin ceramic package

μPA102G: Reduced circuit size due to 14-pin plastic SOP package for surface mounting

DESCRIPTION AND APPLICATIONS

The μ PA102 is a user configurable Silicon bipolar transistor array consisting of two separate differential amplifiers. It is available in a surface mount (14-pin plastic SOP) package and a 14-pin ceramic package. Typical applications include: pulse pattern generators, oscillators, differential amps, high speed comparators, electro-optic signal processing up to 1 Gigabits/second, and advanced cellular phone systems.

ORDERING INFORMATION

PART NUMBER	PACKAGE
μPA102B-E1	14-pin ceramic package
μPA102G-E1	14-pin plastic SOP (225 mil)

ABSOLUTE MAXIMUM RATINGS (TA = +25 °C)

SYMBOLS	PARAMETERS	UNITS	RATINGS	
V _{СВО} *	Collector to Base Voltage	V	15	
Vceo*	Collector to Emitter Voltage	V	6	
V _{EBO} *	Emitter to Base Voltage	V	2.5	
lc*	Collector Current	mA	40	
Рт	Power Dissipation			
	μPA102B	mW	650	
	μPA102G	mW	350	
TJ	Junction Temperature			
	μPA102B	°C	200	
	μPA102G	°C	125	
Тѕтс	Storage Temperature			
	μPA102B	°C	-55 to +200	
	μPA102G	°C	-55 to +125	

^{*} Absolute maximum ratings for each transistor.

Caution electro-static sensitive devices

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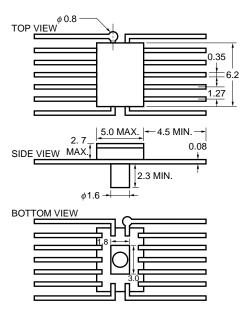
Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.



PACKAGE DIMENSIONS (UNIT: mm)

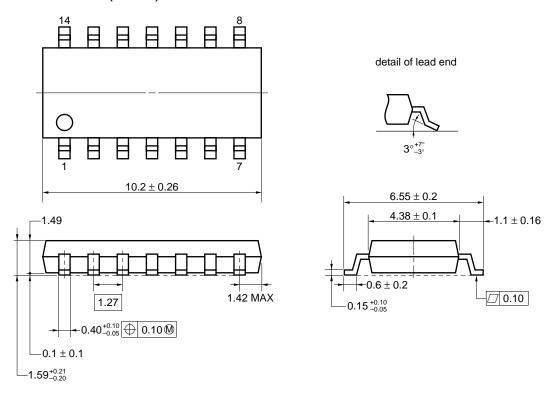
μ PA102B

14 PIN CERAMIC PACKAGE



 μ PA102G

★ 14 PIN PLASTIC SOP (225 mil)



NOTE Each lead centerline is located within 0.10 mm of its true position (T.P.) at maximum material condition.

See connection diagram for description of leads.

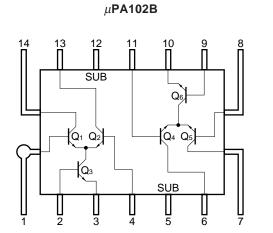


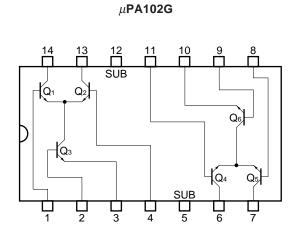
ELECTRICAL CHARACTERISTICS (Unless otherwise specified T_A = +25 °C μPA102B, μPA102G common)

SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN.	TYP.	MAX.
Ісво	Collector Cutoff Current at VcB = 5 V, IE = 0 (Q1, Q2, Q4, Q5)	μΑ			1.0
ІЕВО	Emitter Cutoff Current at V _{EB} = 1 V, I _C = 0 (Q3, Q6)	μΑ			1.0
hfe	Direct Current Amplification at VcE = 3 V, Ic = 1 mA (Q3, Q6)		40	100	250
hFE1/hFE2	Direct Current Amplification Ratio at VcE = 3 V, Ic = 1 mA, (Q3, Q6)		0.9	1.0	1.1
Ссв	Collector to Base Capacitance at VcB = 3 V, f = 1 MHz (Q1, Q2, Q4, Q5)	pF		0.9	1.8
СЕВ	Emitter to Base Capacitance at VEB = 0, f = 1 MHz (Q3, Q6)	pF		1.4	2.8
Ccs	Collector/Substrate Capacitance at Vcs = 3 V, f = 1 MHz (Q1, Q2, Q4, Q5)	pF		1.4	2.8
f⊤	Gain Bandwidth Product* at VcE = 3 V, Ic = 10 mA	GHz		9.0	

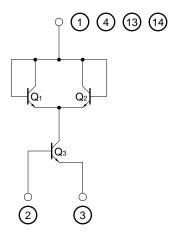
^{*} Measured by installing a single transistor in a Micro-X package: the value shown is a reference value.

CONNECTION DIAGRAM (Top View)





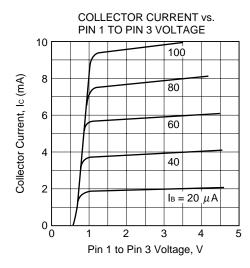
TEST CIRCUIT SCHEMATIC* (For Electrical Characteristics Measurements excluding ft)

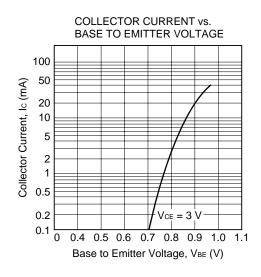


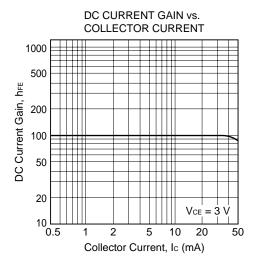
^{*} See performance characteristics for voltage.

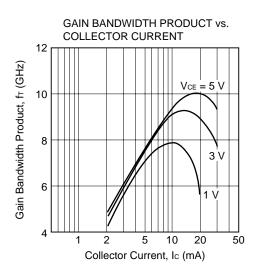


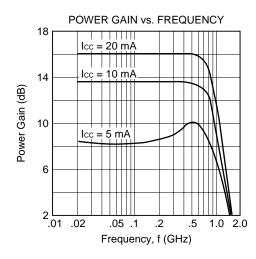
TYPICAL PERFORMANCE CHARACTERISTICS (TA = +25 °C)

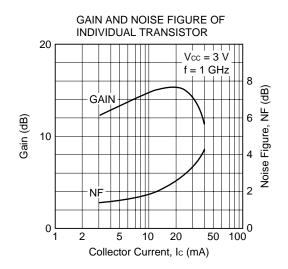














NOTES ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as wide as possible to minimize ground impedance (to prevent undesired operation).
- (3) Design circuits connected Sub pin to the lowest voltage to prevent latch-up.
- (4) Design circuits as each pin voltage difference within 15 V maximum.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered in the following recommended conditions. Other soldering methods and conditions than the recommended conditions are to be consulted with our sales representatives.

μ PA102G

Soldering process	Soldering conditions	Recommended condition symbol
Infrared ray reflow	Package peak temperature: 235 °C, Hour: within 30 s. (more than 210 °C), Time: 2 times, Limited days: no. Note	IR35-00-2
VPS	Package peak temperature: 215 °C, Hour: within 40 s. (more than 200 °C), Time: 2 times, Limited days: no. Note	VP15-00-2
Wave soldering	Soldering tub temperature: less than 260 °C, Hour: within 10 s. Time: 1 time, Limited days: no. Note	WS60-00-1
Pin part heating	Pin area temperature: less than 300 °C, Hour: within 3 s./pin Limited days: no. Note	

μ PA102B

Soldering process	Soldering conditions	Symbol
Infrared ray reflow	Peak package's surface temperature: 230 °C or below, Reflow time: 10 seconds or below (210 °C or higher), Number of reflow process: 1, Exposure limit*: None	
Partial heating method	Terminal temperature: 260 °C or below, Flow time: 10 seconds or below, Exposure limit*: None	

Note It is the storage days after opening a dry pack, the storage conditions are 25 °C, less than 65 % RH.

Caution The combined use of soldering method is to be avoided (However, except the pin area heating method).

For details of recommended soldering conditions for surface mounting, refer to information document SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E).

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[MEMO]

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 - Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
 - Specific: Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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